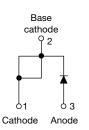


Vishay Semiconductors

Schottky Rectifier, 10 A





TO-220AC

PRODUCT SUMMARY							
Package	TO-220AC						
I _{F(AV)}	10 A						
V _R	35 V, 40 V, 45 V						
V _F at I _F	0.49 V						
I _{RM}	15 mA at 125 °C						
T _J max.	175 °C						
Diode variation	Single die						
E _{AS}	13 mJ						

FEATURES

- 175 °C TJ operation
- Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance



- chanical RoHS COMPLIANT and long
- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

DESCRIPTION

The VS-10TQ... Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I _{F(AV)}	Rectangular waveform	10	A						
V _{RRM}		35/45	V						
I _{FSM}	t _p = 5 μs sine	1050	A						
V _F	10 A _{pk} , T _J = 125 °C	0.49	V						
TJ	Range	- 55 to 175	۵°C						

VOLTAGE RATINGS									
PARAMETER	SYMBOL	VS- 10TQ035PbF	VS- 10TQ035-N3	VS- 10TQ040PbF	VS- 10TQ040-N3	VS- 10TQ045PbF	VS- 10TQ045-N3	UNITS	
Maximum DC reverse voltage	V _R								
Maximum working peak reverse voltage	V _{RWM}	35	35	40	40	45	45	V	

ABSOLUTE MAXIMUM RATINGS										
PARAMETER	SYMBOL	TEST COND	VALUES	UNITS						
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at $T_C = 151$ °C	10							
Maximum peak one cycle non-repetitive surge current		5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	1050	А					
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	V_{RRM} applied	280						
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 2 A, L = 6.5 n	13	mJ						
Repetitive avalanche current	I _{AR}	Current decaying linearly to ze Frequency limited by T_J maxim	2	А						

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ELECTRICAL SPECIFICATIONS										
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS						
Maximum forward voltage drop See fig. 1		10 A	T ₁ = 25 °C	0.57						
	V _{FM} ⁽¹⁾	20 A	1j=25 0	0.67	V					
	V FM (*)	10 A	T, = 125 °C	0.49						
		20 A	$1_{\rm J} = 125$ C	0.61						
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	2	mA					
See fig. 2	IRM (')	T _J = 125 °C	$v_{\rm R} = nateu v_{\rm R}$	15	mA					
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal ran	900	pF						
Typical series inductance	L _S	Measured lead to lead 5 r	8.0	nH						
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs					

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,\,duty\,cycle$ < 2 $\,\%$

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction and storage temperature range		T _J , T _{Stg}		- 55 to 175	°C				
Maximum thermal resistance, junction to case		R _{thJC}	DC operation See fig. 4	2.0	°C/W				
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50					
Approximate weight				2	g				
Approximate weight				0.07	oz.				
Mounting torque	minimum			6 (5)	kgf ⋅ cm				
Mounting torque	maximum			12 (10)	(lbf · in)				
Marking daviaa					Q035				
Warking device	Marking device		Case style TO-220AC	10TQ045					



VS-10TQ...PbF Series, VS-10TQ...-N3 Series

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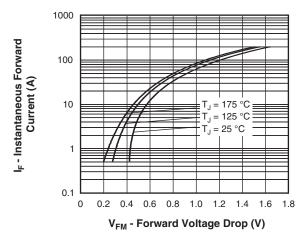


Fig. 1 - Maximum Forward Voltage Drop Characteristics

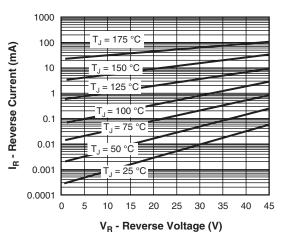


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

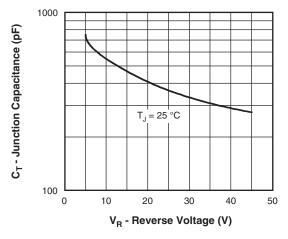
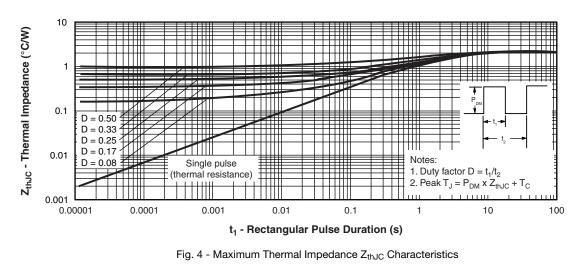


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

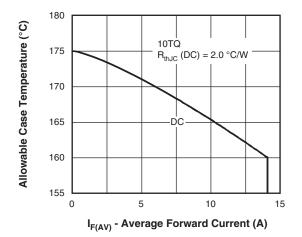


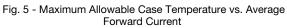
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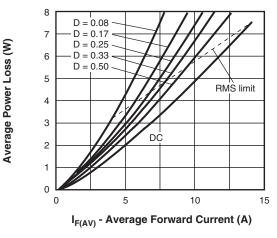


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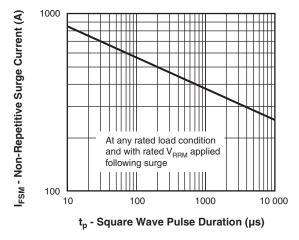


Fig. 7 - Maximum Non-Repetitive Surge Current

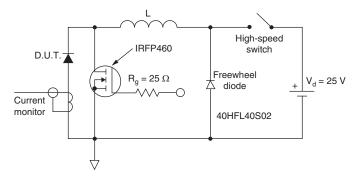


Fig. 8 - Unclamped Inductive Test Circuit



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ORDERING INFORMATION TABLE

Device code	VS-	10	т	Q	045	PbF
	1	2	3	4	5	6
	1 2 3 -	Cur Pac T =	rent rati kage: TO-220		= 10 A)	oduct
	4 - 5 - 6 -	Volt	age rati	ı" series ngs — ntal digit		(
		• F	bF = Le	ad (Pb)	-free an	d RoHS

• -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)										
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION							
VS-10TQ035PbF	50	1000	Antistatic plastic tube							
VS-10TQ035-N3	50	1000	Antistatic plastic tube							
VS-10TQ040PbF	50	1000	Antistatic plastic tube							
VS-10TQ040-N3	50	1000	Antistatic plastic tube							
VS-10TQ045PbF	50	1000	Antistatic plastic tube							
VS-10TQ045-N3	50	1000	Antistatic plastic tube							

LINKS TO RELATED DOCUMENTS						
Dimensions		www.vishay.com/doc?95221				
Part marking information	TO-220ACPbF	www.vishay.com/doc?95224				
	TO-220AC-N3	www.vishay.com/doc?95068				



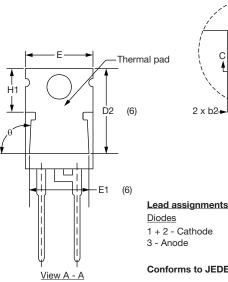
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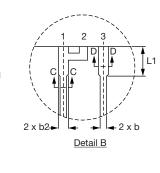
TO-220AC

plane

DIMENSIONS in millimeters and inches









Diodes 1 + 2 - Cathode 3 - Anode

Conforms to JEDEC outline TO-220AC

⊕ 0.015 **()** BA()

SYMBOL	MILLIM	IETERS	INC	HES	NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STMBUL	MIN.	MAX.	MIN.	MAX.	NOTES	OTMEDEL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183		E1	6.86	8.89	0.270	0.350	6
A1	1.14	1.40	0.045	0.055		E2	-	0.76	-	0.030	7
A2	2.56	2.92	0.101	0.115		е	2.41	2.67	0.095	0.105	
b	0.69	1.01	0.027	0.040		e1	4.88	5.28	0.192	0.208	
b1	0.38	0.97	0.015	0.038	4	H1	6.09	6.48	0.240	0.255	6, 7
b2	1.20	1.73	0.047	0.068		L	13.52	14.02	0.532	0.552	
b3	1.14	1.73	0.045	0.068	4	L1	3.32	3.82	0.131	0.150	2
с	0.36	0.61	0.014	0.024		L3	1.78	2.13	0.070	0.084	
c1	0.36	0.56	0.014	0.022	4	L4	0.76	1.27	0.030	0.050	2
D	14.85	15.25	0.585	0.600	3	ØР	3.54	3.73	0.139	0.147	
D1	8.38	9.02	0.330	0.355		Q	2.60	3.00	0.102	0.118	
D2	11.68	12.88	0.460	0.507	6	θ	90° t	o 93°	90° t	o 93°	
E	10.11	10.51	0.398	0.414	3, 6						

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

- ⁽²⁾ Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- ⁽⁴⁾ Dimension b1, b3 and c1 apply to base metal only
- ⁽⁵⁾ Controlling dimension: inches
- ⁽⁶⁾ Thermal pad contour optional within dimensions E, H1, D2 and E1
- ⁽⁷⁾ Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- ⁽⁸⁾ Outline conforms to JEDEC TO-220, D2 (minimum) where dimensions are derived from the actual package outline



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